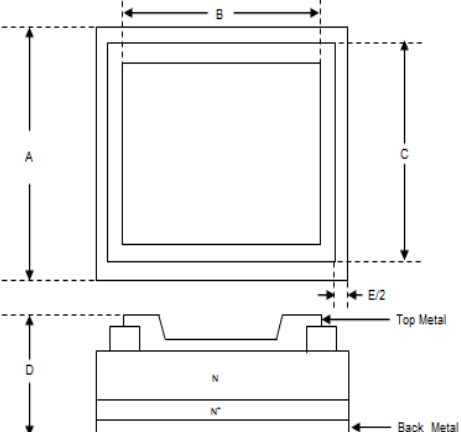




PMB134T045SS-255A

20A/45V⁽¹⁾, low VF Planar MOS barrier diode

Mechanical Data

Chip Drawing	Item	Information	
	Die Size (A)	3404μm	134.0 mil
	Top Metal Pad Size (B)	3284μm	129.3mil
	Chip Size (C)	/	/
	Wafer Thickness (D)	255 μm	10.0 mil
	Scribe Line Width (E)	80 μm	3.15 mil
	Wafer Size	6 inch	
	Top Side Metallization	PMB134T045SS-255A	Ag
	Back Side Metallization	Ti Ni Ag	